

Today's outline - October 12, 2021



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- Crystal truncation rods

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- Diffuse Scattering

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Reading Assignment: Chapter 5.5-5.6

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Homework Assignment #04:

Chapter 4: 2,4,6,7.10

due Tuesday, October 19, 2021

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- Crystal truncation rods
- Diffuse Scattering
- Modulated structures
- Lattice vibrations

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Homework Assignment #04:

Chapter 4: 2,4,6,7,10

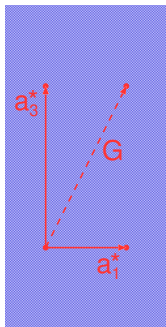
due Tuesday, October 19, 2021

Homework Assignment #05:

Chapter 5: 1,3,7,9,10

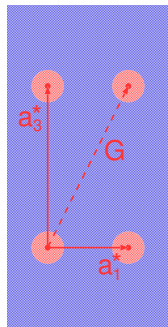
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Diffraction from a Truncated Surface



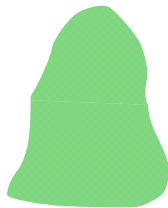
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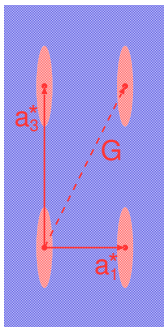
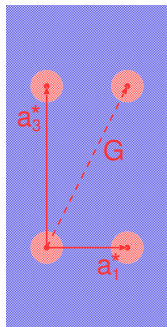


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With finite sample size, these spots grow in extent and become more diffuse.



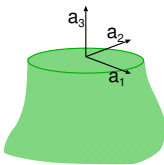
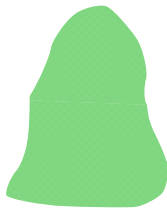
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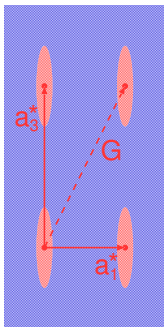
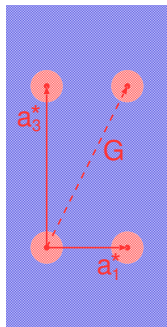
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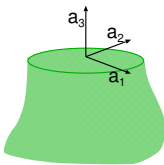
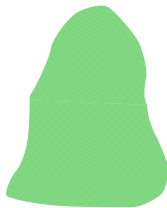
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The scattering intensity can be obtained by treating the charge distribution as a convolution of an infinite sample with a step function in the z -direction.

CTR Scattering Factor



The scattering amplitude F^{CTR} along a crystal truncation rod is given by summing an infinite stack of atomic layers, each with scattering amplitude $A(\vec{Q})$.

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Dependence on Q



When l is an integer (meeting the Laue condition), the scattering factor is infinite but just off this value, the scattering factor can be computed by letting $Q_z = q_z + 2\pi/a_3$, with q_z small.

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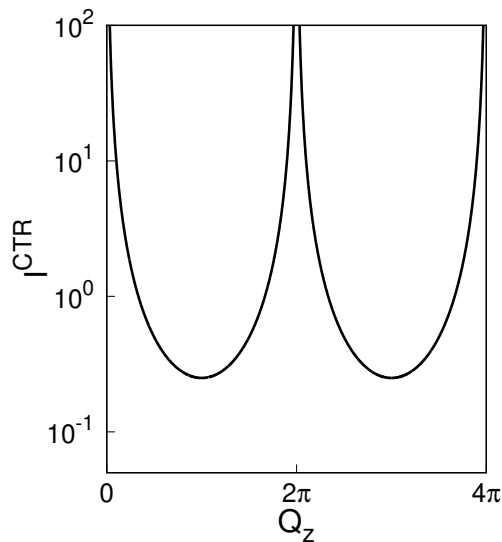
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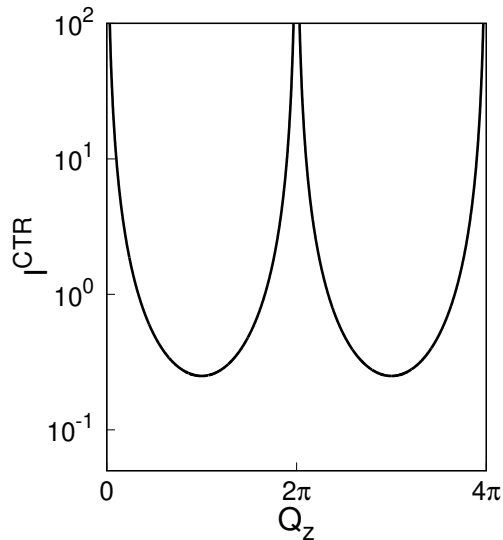
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Absorption Effect



Absorption effects can be included as well by adding a term for each layer penetrated

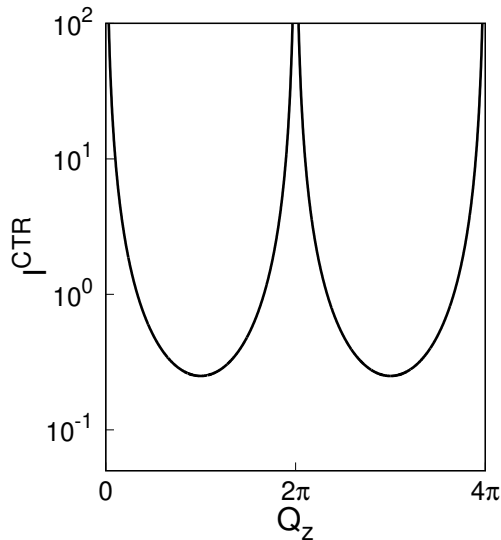


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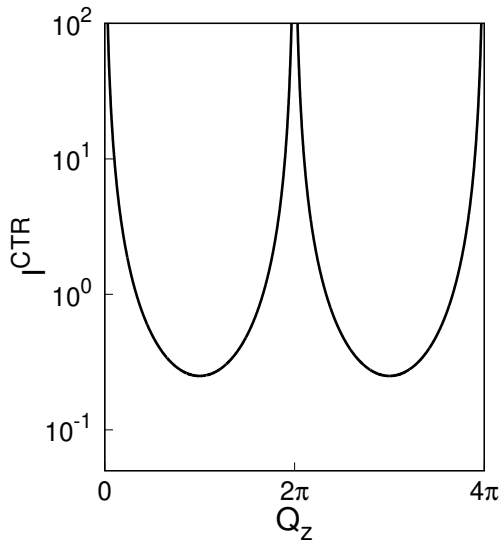


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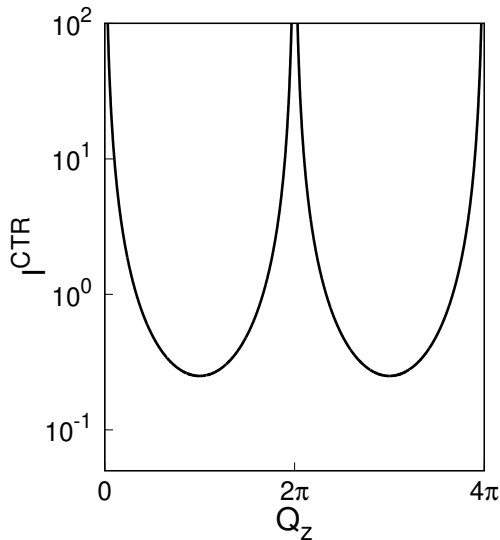


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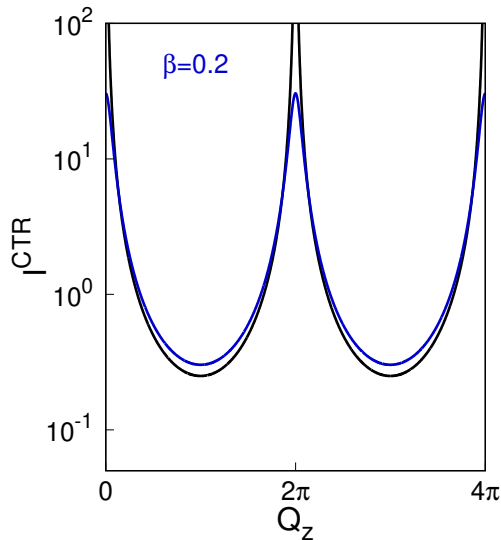


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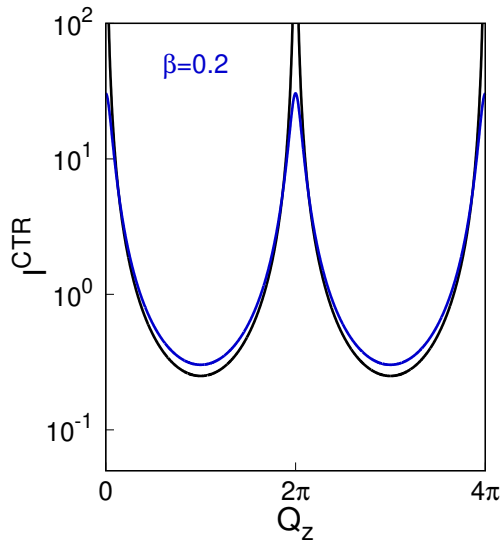
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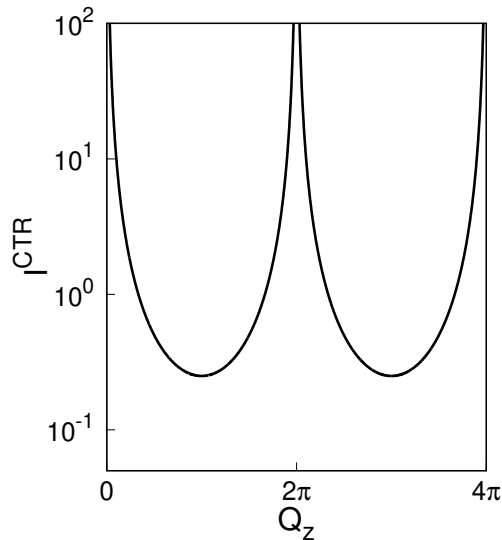
This removes the infinity and increases the scattering profile of the crystal truncation rod



Density Effect



The CTR profile is sensitive to the termination of the surface. This makes it an ideal probe of electron density of adsorbed species or single atom overlayers.

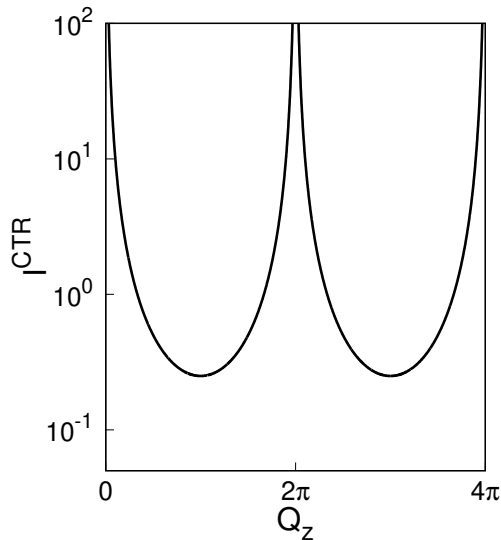


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$$F^{total} = F^{CTR} + F^{top\ layer}$$

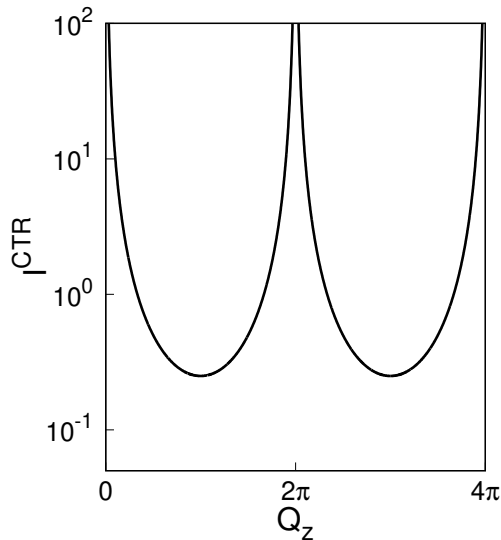


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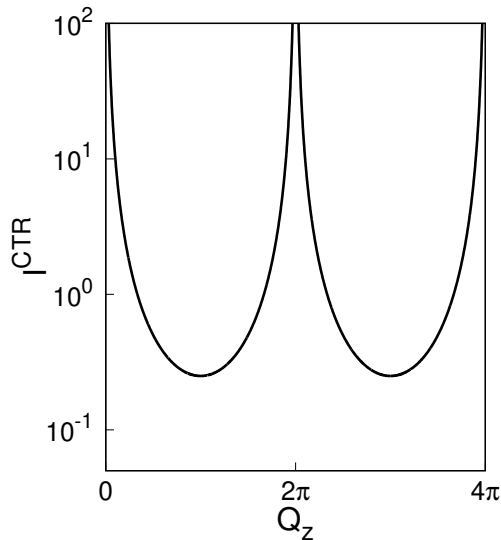


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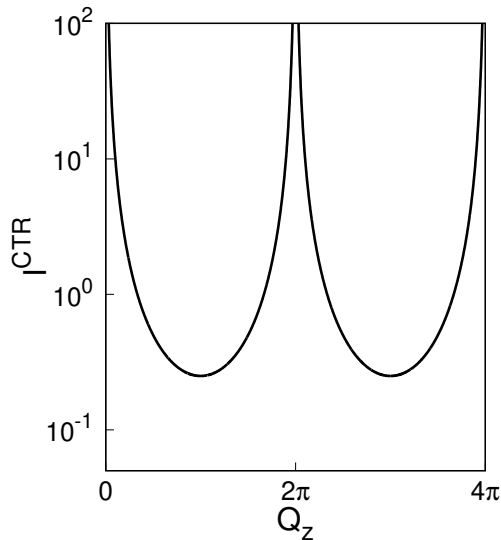
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where z_0 is the relative displacement of the top layer from the bulk lattice spacing a_3



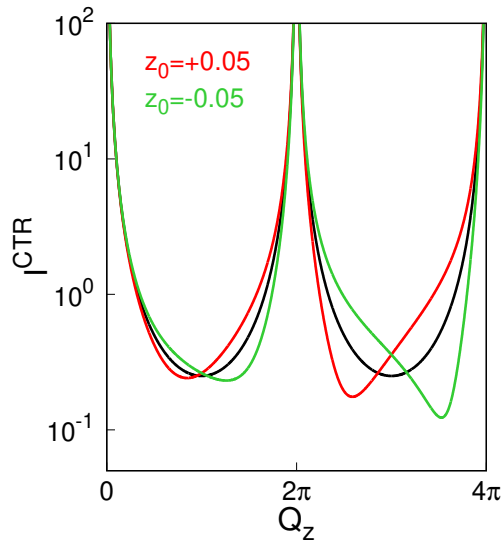
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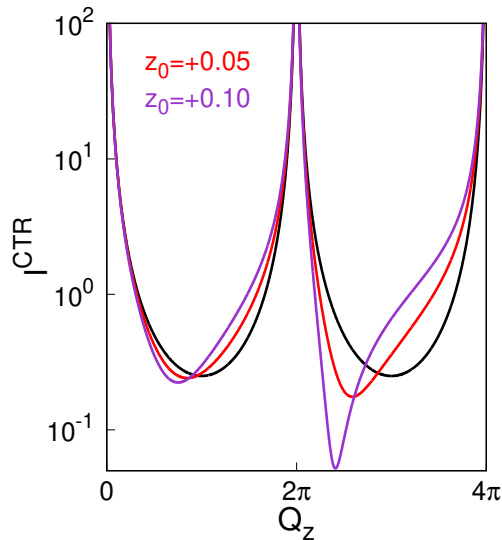


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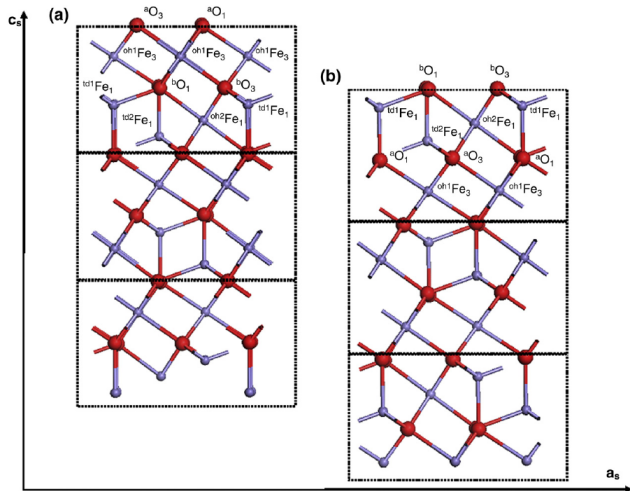
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This effect gets larger for larger momentum transfers

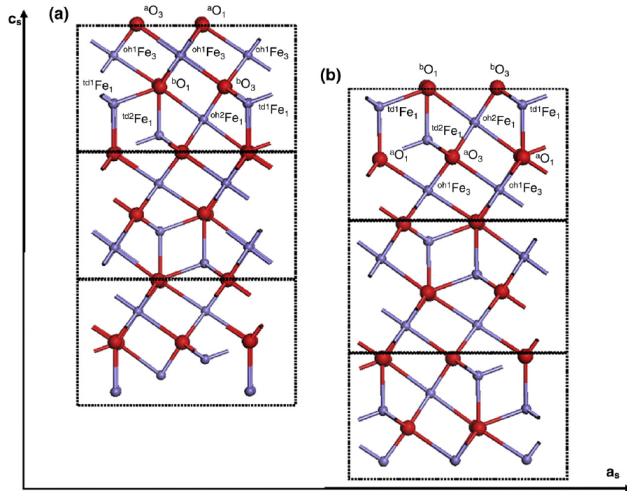


Hydrated surface of magnetite



"Surface structure of magnetite (111) under hydrated conditions by crystal truncation rod diffraction," S.C. Petitto et al. *Surf. Sci.* **604**, 1082-1093 (2010).

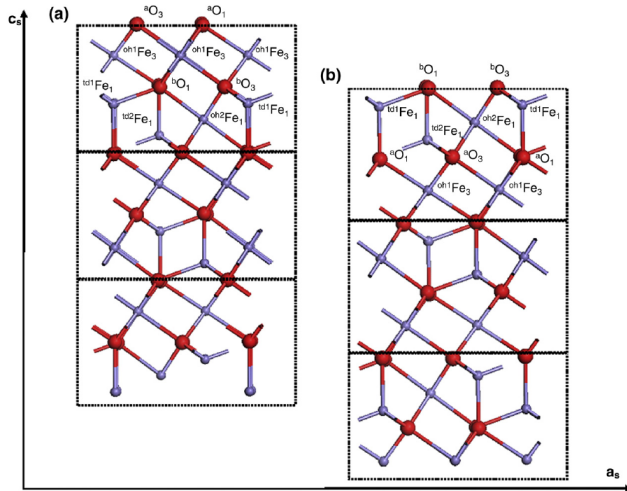
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Magnetite, Fe_3O_4 , is a technologically important material for environmental remediation

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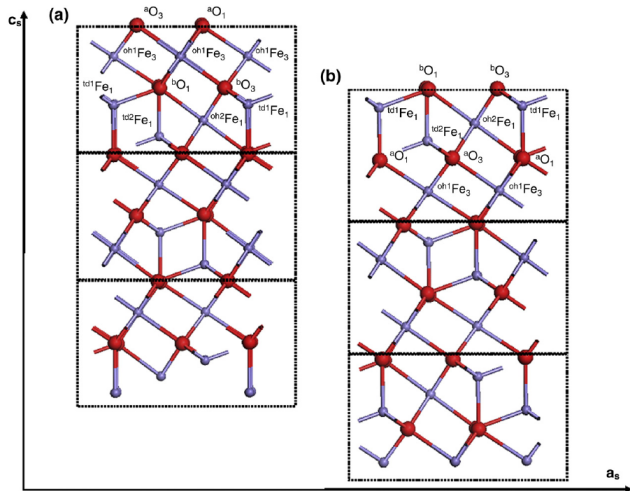


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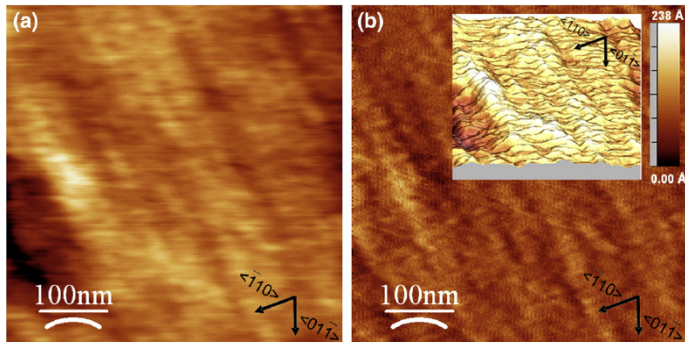
There are two possible surfaces, the oxygen octahedral iron, OOI (a), and the oxygen mixed-iron, OMI (b), terminations

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Magnetite (111) surface



Crystal truncation rod measurements require an oriented single crystal with a polished and cleaned surface.

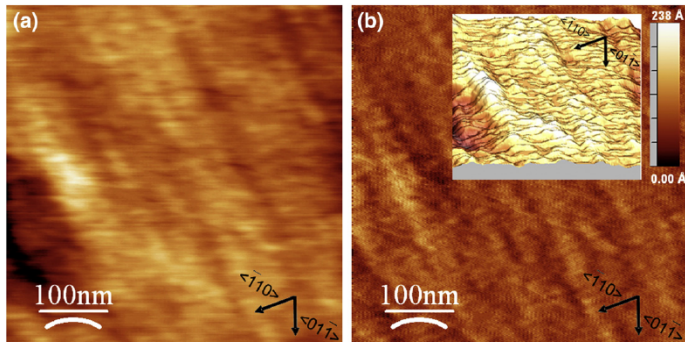


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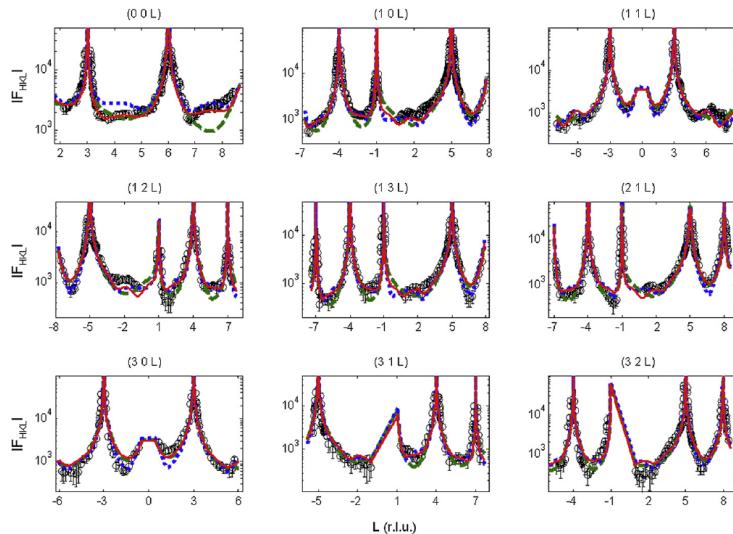
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The final polished surface has clear terraces of between 150 Å–700 Å and a surface roughness of about 1.4 Å as seen in the inset from the atomic force microscopy images

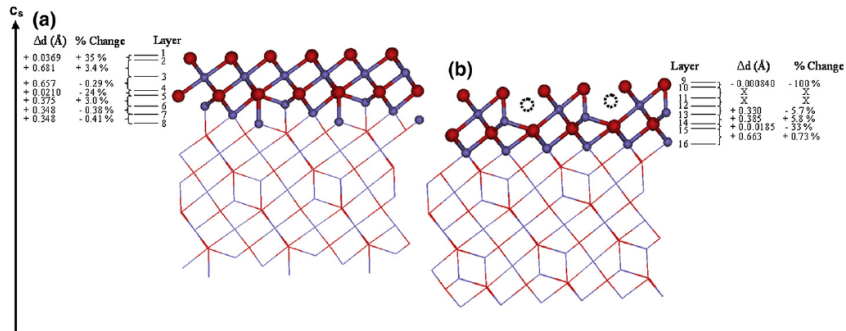
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CTR data and modeling



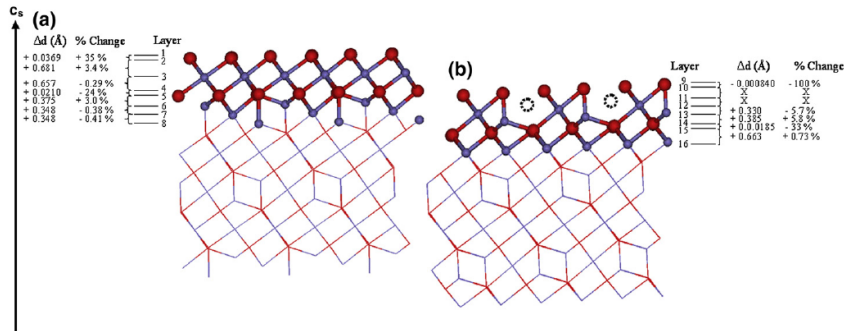
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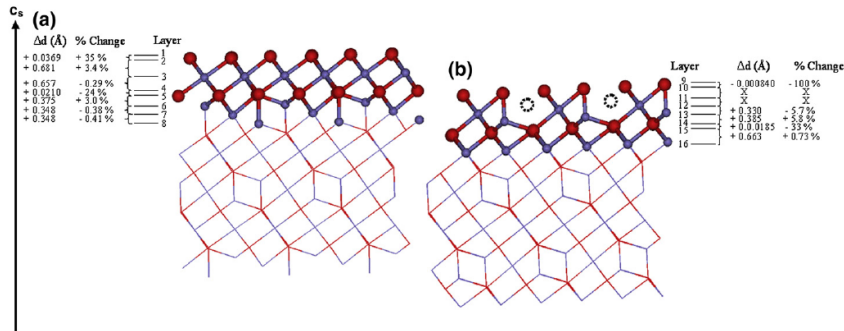
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The result of the modeling of the CTR data indicates that the surface is 75% OOI and 25% OMI

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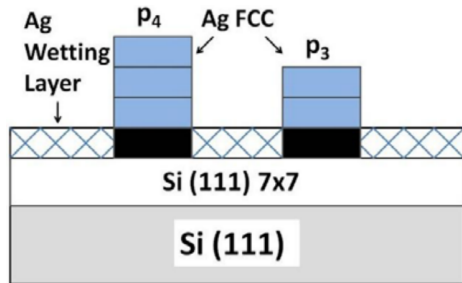


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The modeling also can provide details about the distance changes in the first layers at the surface

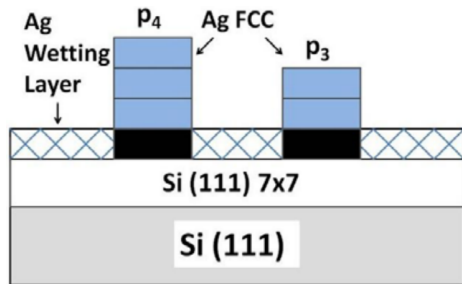
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Buried interfaces of Ag films on silicon



"Critical role of a buried interface in the Stranski-Krastanov growth of metallic nanocrystals: Quantum size effects in Ag/Si(111)-(7×7)," Y. Chen et al. *Phys. Rev. Lett.* **114**, 035501 (2015).

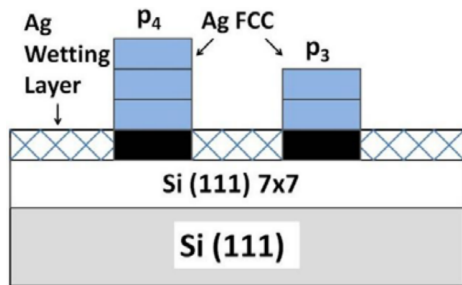
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Understanding the process of surface wetting during thin film deposition is crucial to the semiconductor industry

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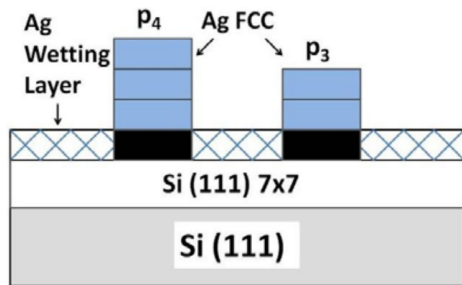


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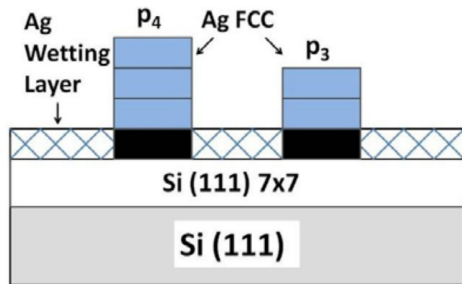
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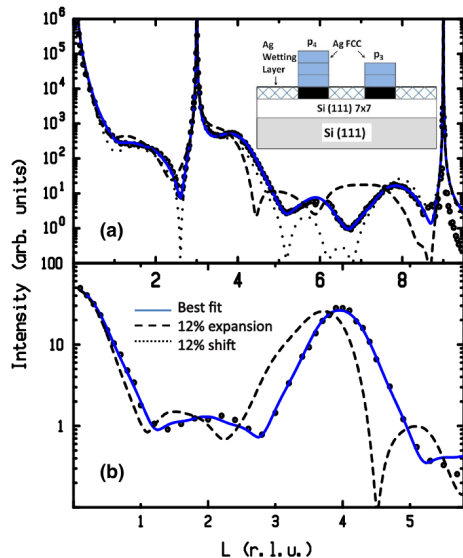
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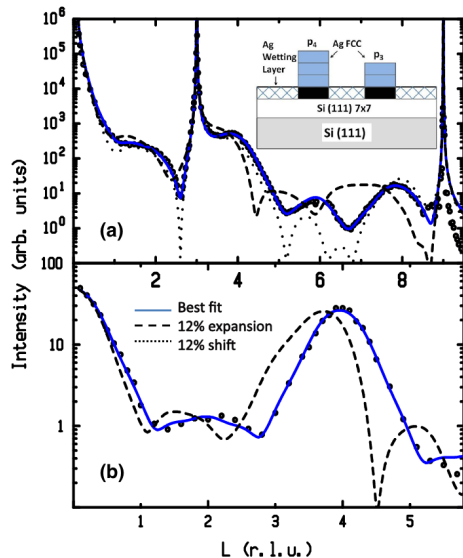
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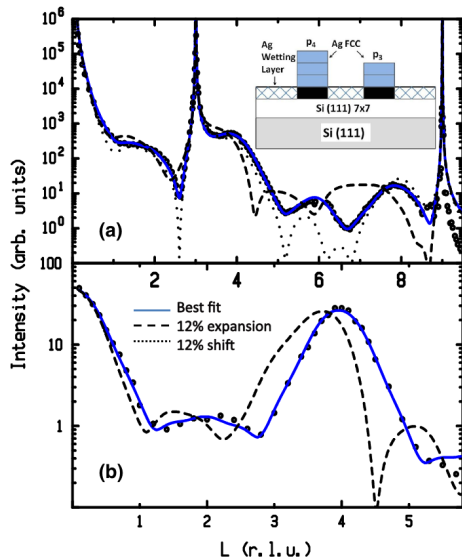
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Reflectivity “sees” the entire surface while CTR measures only the incommensurate Ag crystalline layer on the surface

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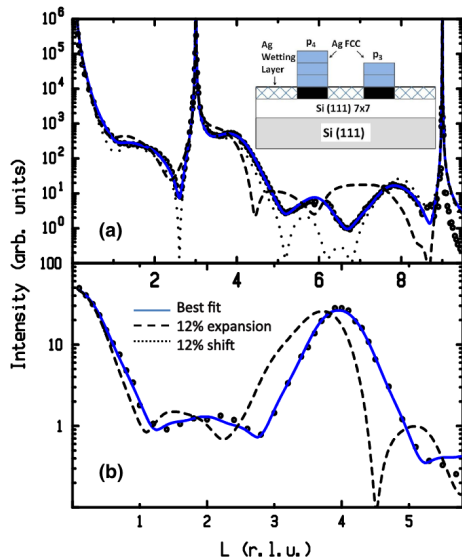


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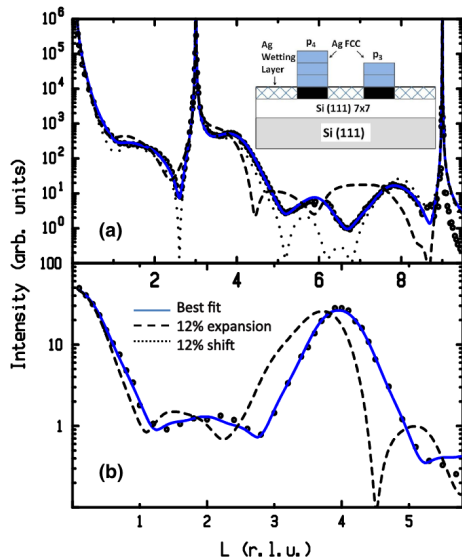
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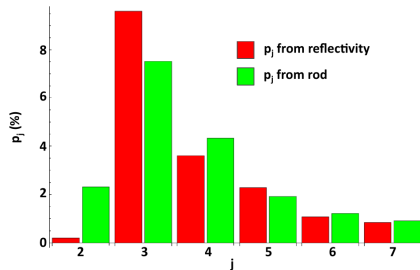
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Modeling shows that the islands are displaced from the surface

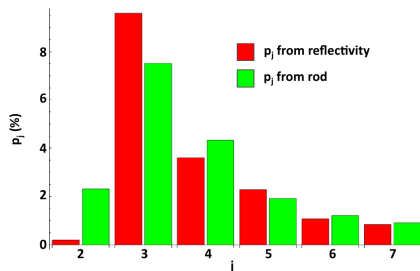
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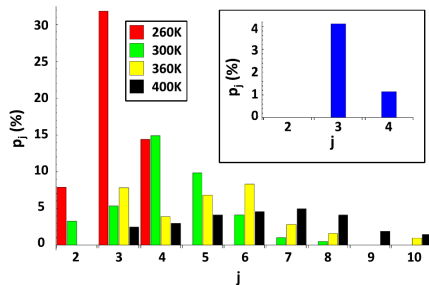
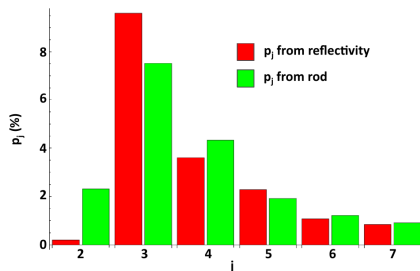
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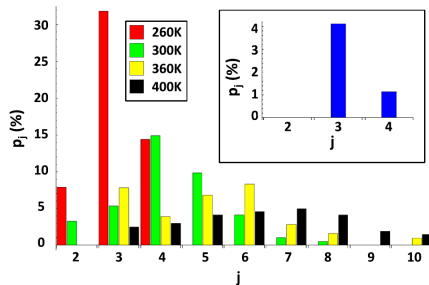
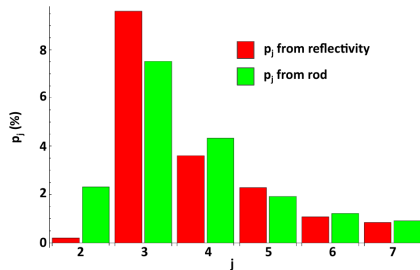
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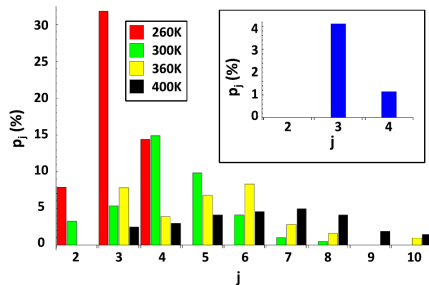
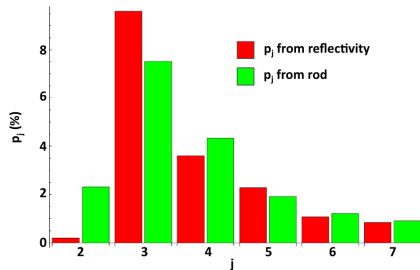


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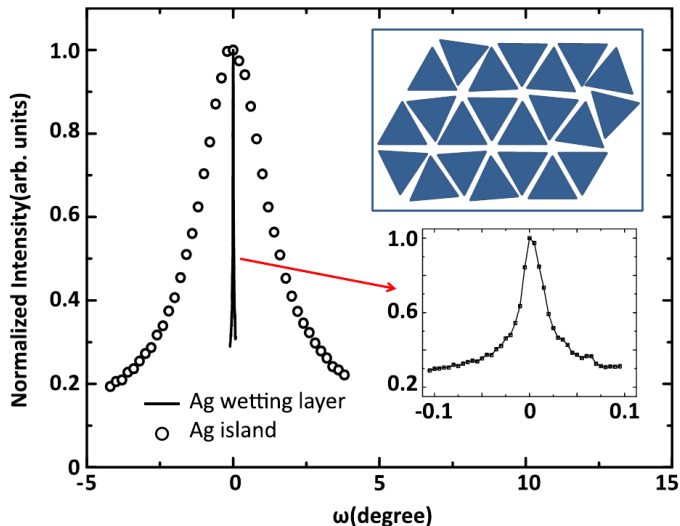
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The exceptional stability of the three layer islands is consistent with quantum confinement effects that drive the growth process

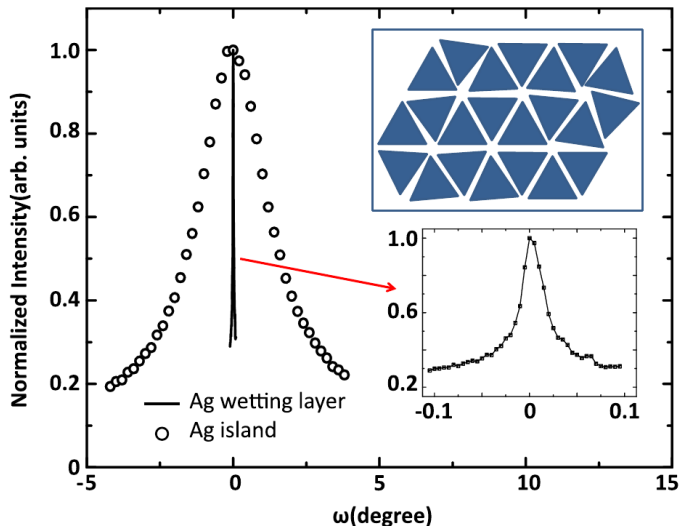
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In plane structure of islands



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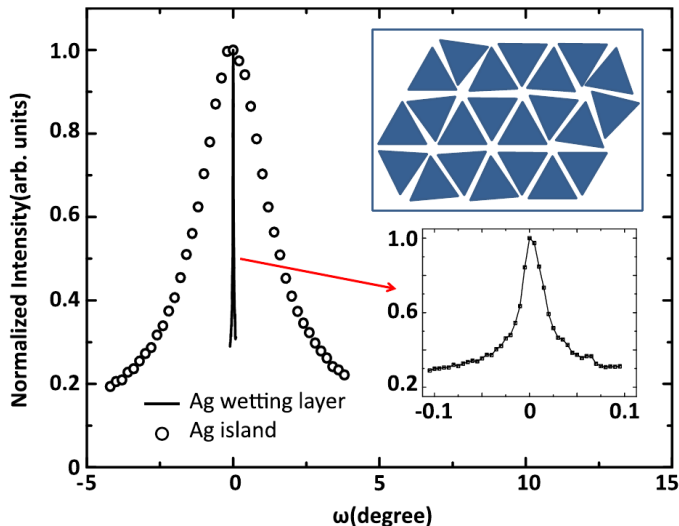
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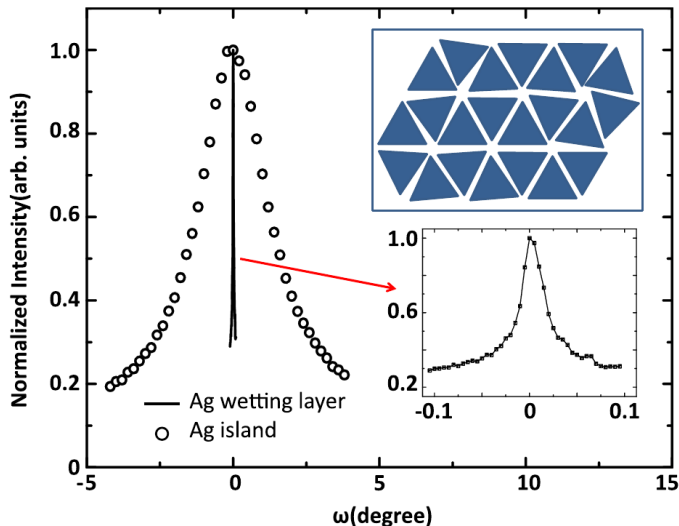
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The islands thus have a weak interaction with the substrate compared to the wetting layer.

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However, it is common to see structures where the positions of the atoms is modulated (e.g. charge density waves, magnetic lattices, etc.) according to $x_n = an + u \cos(qan)$, where: a is the lattice parameter, u is the amplitude of the displacement, and $q = 2\pi/\lambda_m$ is the wave vector of the modulation.



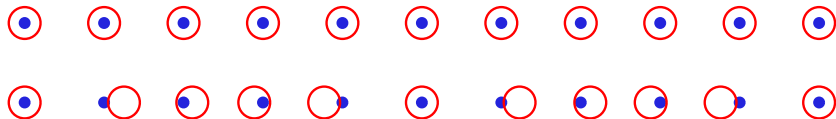
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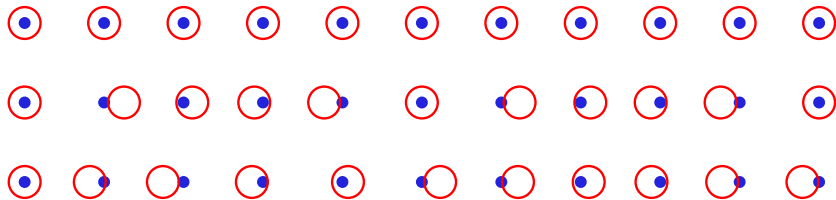
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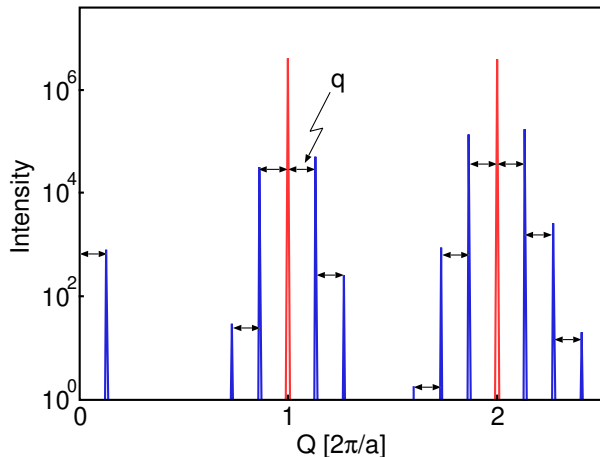


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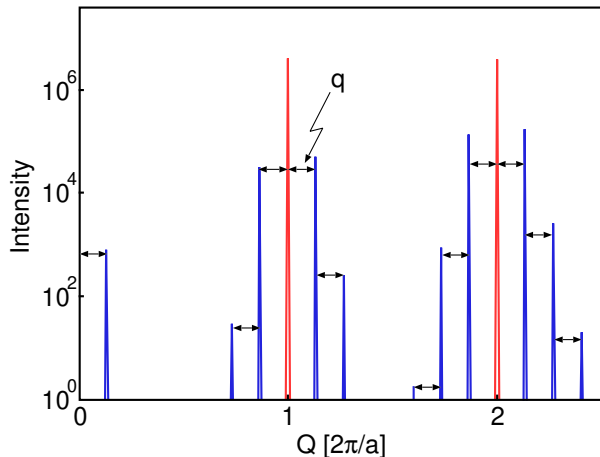


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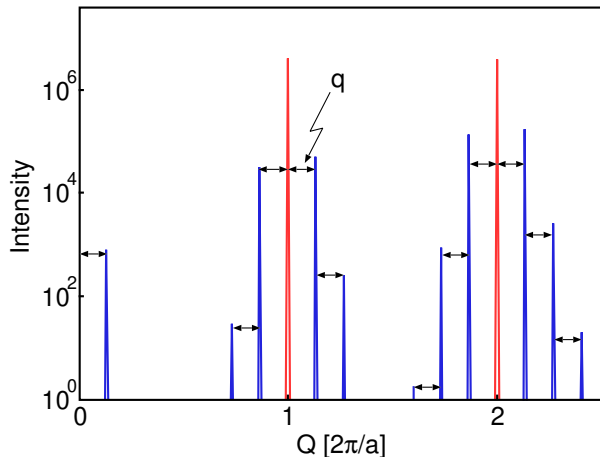
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If the modulation of the structure is a multiple of the lattice parameter, the modulation is simply a superlattice and the actual lattice parameter will be changed.





The only rotational symmetries which permit a space-filling lattice are 2-, 3-, 4-, and 6-fold.



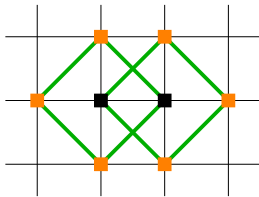
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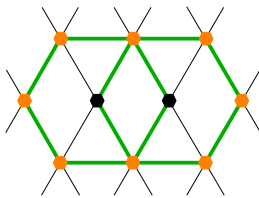
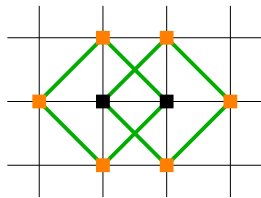
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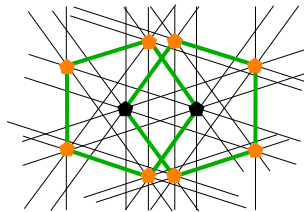
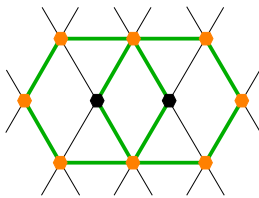
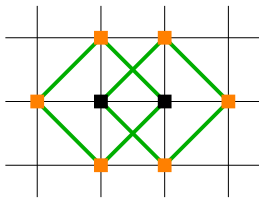


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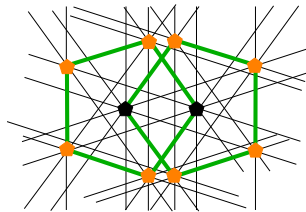
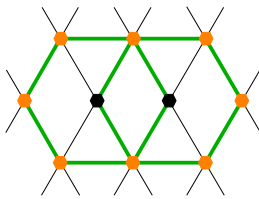
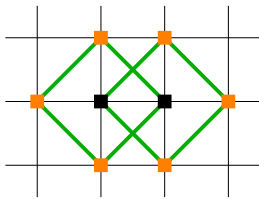


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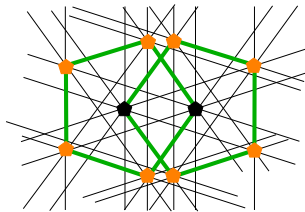
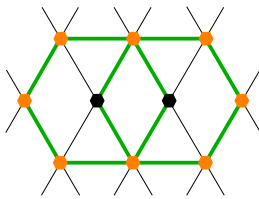
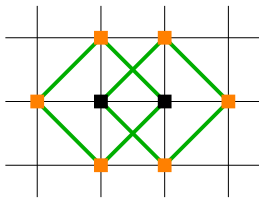
Initially this result was not accepted but as many new materials with the same were discovered it was clear that a new kind of crystal had been discovered.

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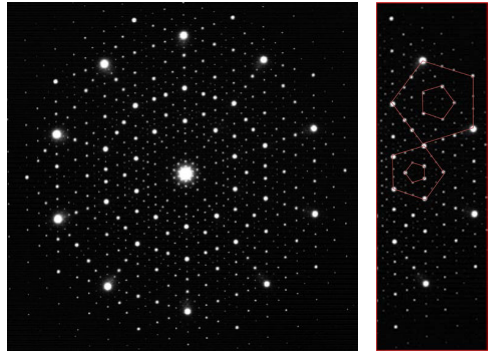
Initially this result was not accepted but as many new materials with the same were discovered it was clear that a new kind of crystal had been discovered.

In 2011 Shechtman was awarded the Nobel Prize in Chemistry

5-fold symmetry



The electron micrographs show that there must be long range order to be able to get such sharp diffraction peaks



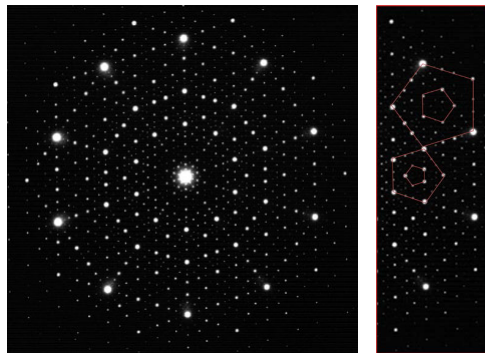
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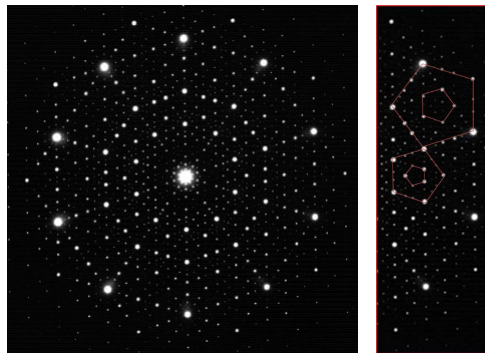
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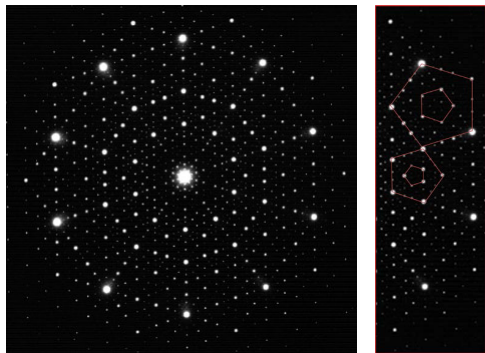
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Other groups have discovered stable icosahedral phases with three and two elements.

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Quasicrystal diffraction patterns



The $\text{Al}_{65}\text{Cu}_{20}\text{Fe}_{15}$ system was one of the first stable quasicrystals to be discovered. Later discovery of stable quasicrystals in the Ta-Te, Cd-Ca, and Cd-Yb systems enabled large crystals to be grown.

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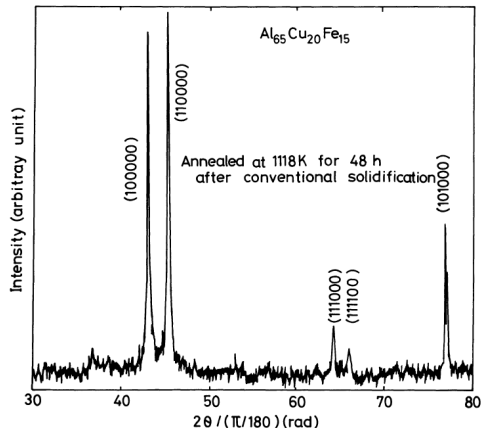
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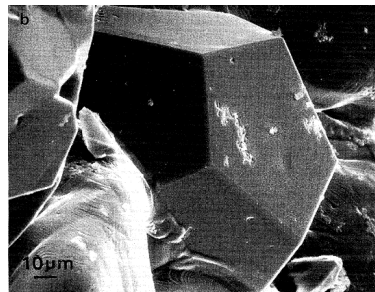
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The last term is a time average which can be simplified by first taking the scalar product, $\vec{Q} \cdot \vec{u}_n = u_{Qn}$ to project the displacement along the scattering vector, then applying the Baker-Hausdorff theorem, $\langle e^{ix} \rangle = e^{-\langle x^2 \rangle / 2}$



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$$\left\langle e^{iQ(u_{Qm}-u_{Qn})} \right\rangle = e^{-Q^2 \langle u_{Qm}^2 \rangle / 2} e^{-Q^2 \langle u_{Qn}^2 \rangle / 2} e^{Q^2 \langle u_{Qm} u_{Qn} \rangle}$$



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The first term is just the elastic scattering from the lattice with the addition of the term $e^{-M} = e^{-Q^2 \langle u_Q^2 \rangle / 2}$, called the Debye-Waller factor.



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The second term is the Thermal Diffuse Scattering and actually increases with mean squared displacement.